

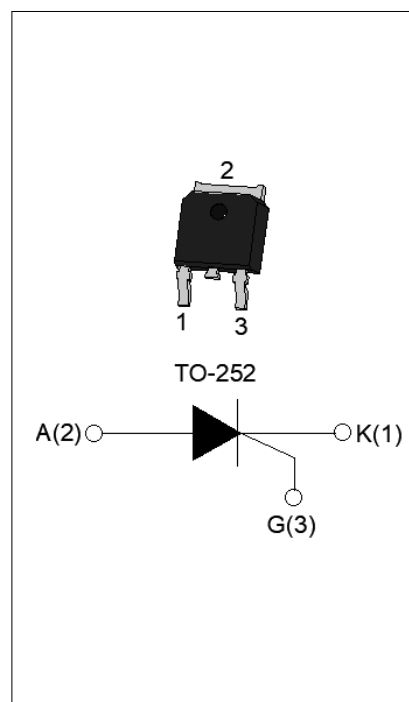


### DESCRIPTION:

With high ability to withstand the shock loading of large current, JCT1612K provides high  $dV/dt$  rate with strong resistance to electromagnetic interference. It is especially recommended for use on hair straightener, motorcycle voltage regulators etc. Package TO-252 is RoHS compliant.

### MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$	12	A
$V_{DRM}/V_{RRM}$	1600	V
$I_{GT}$	15	mA



### ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	$T_{stg}$	-40-150	
Operating junction temperature range	$T_j$	-40-125	
Repetitive peak off-state voltage ( $T_j=25^\circ C$ )	$V_{DRM}$	1600	V
Repetitive peak reverse voltage ( $T_j=25^\circ C$ )	$V_{RRM}$	1600	V
Average on-state current ( $T_c = 72^\circ C$ )	$I_{T(AV)}$	7.5	A
RMS on-state current ( $T_c = 72^\circ C$ )	$I_{T(RMS)}$	12	A
Non repetitive surge peak on-state current ( $t_p=10ms, T_j=25^\circ C$ )	$I_{TSM}$	120	A
Non repetitive surge peak on-state current ( $t_p=8.3ms, T_j=25^\circ C$ )		130	
$I^2t$ value for fusing ( $t_p=10ms, T_j=25^\circ C$ )	$I^2t$	72	$A^2s$
Critical rate of rise of on-state current ( $I_G=2 \times I_{GT}, f=100Hz, T_j=125^\circ C$ )	$di/dt$	100	$A/\mu s$
Peak gate current ( $t_p=20\mu s, T_j=125^\circ C$ )	$I_{GM}$	4	A

Average gate power dissipation ( $T_j=125$ )	$P_{G(AV)}$	1	W
Peak gate power	$P_{GM}$	5	W
Peak pulse voltage ( $T_j=25$ ; non-repetitive, off-state; FIG.8)	$V_{pp}$	1.8	kV

**ELECTRICAL CHARACTERISTICS** ( $T_j=25$  unless otherwise specified)

Symbol	Test Condition	Value			Unit
		MIN.	TYP.	MAX.	
$I_{GT}$	$V_D=12V$ $R_L=33$	-	-	15	mA
$V_{GT}$		-	-	1	V

**ORDERING INFORMATION**

<b>J</b>	<b>CT</b>	<b>16</b>	<b>12</b>	<b>K</b>	<b>-/</b>
JieJie Microelectronics Co., Ltd.	SCRs	16:VDRM/VRRM 1600V	IT(RMS):12A	K:TO-252	Blank:Tube -TR:Tape & Reel

**MARKING**

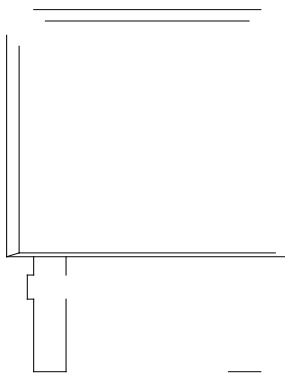




FIG.7: Relative variations of gate trigger current, holding current and latching current versus junction temperature

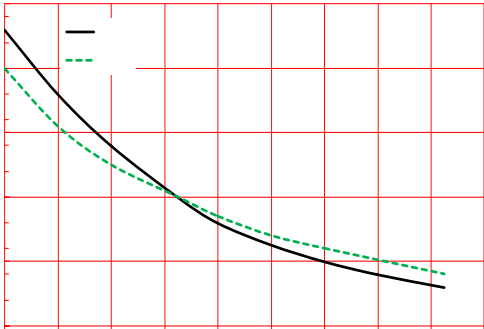
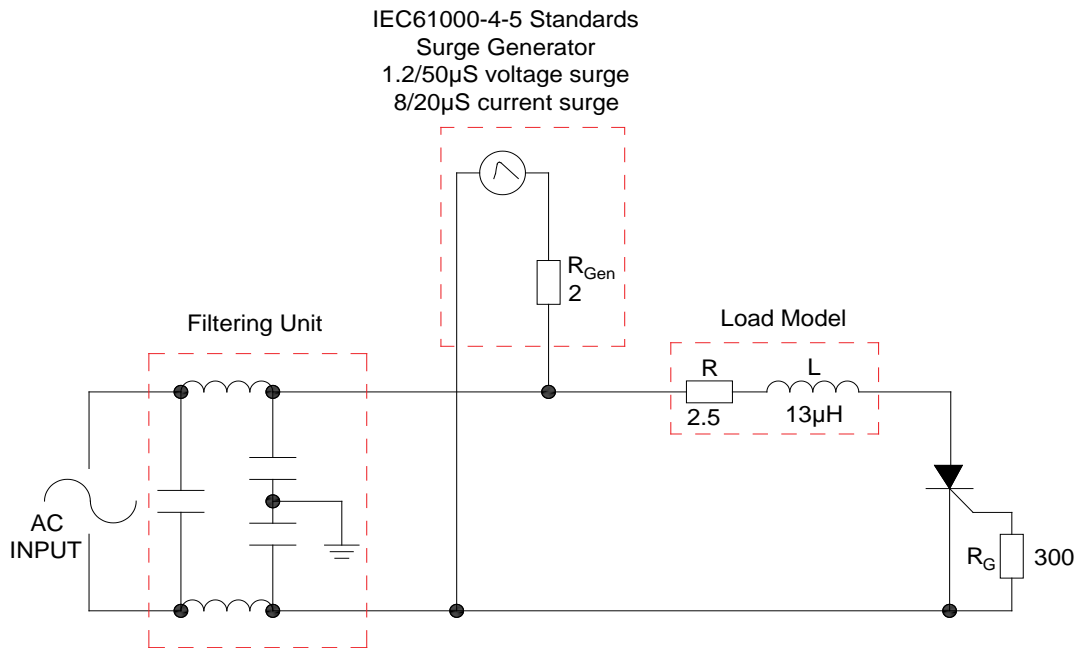


FIG.8 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards.



**SOLDERING PARAMETERS**

Reflow Condition		Pb-Free assembly (see figure at right)
Pre Heat	-Temperature Min ( $T_{s(min)}$ )	+150
	-Temperature Max( $T_{s(max)}$ )	+200
	-Time (Min to Max) (ts)	60-180 secs.
Average ramp up rate (Liquidus Temp ( $T_L$ ) to peak)		3 /sec. Max
$T_{s(max)}$ to $T_L$ - Ramp-up Rate		3 /sec. Max
Reflow	-Temperature( $T_L$ ) (Liquidus)	+217
	-Temperature( $t_L$ )	60-150 secs.
Peak Temp ( $T_p$ )		+260(+0/-5)
Time within 5 of actual Peak Temp ( $t_p$ )		20-40secs.
Ramp-down Rate		6 /sec. Max
Time 25 to Peak Temp ( $T_p$ )		8 min. Max

Do not exceed

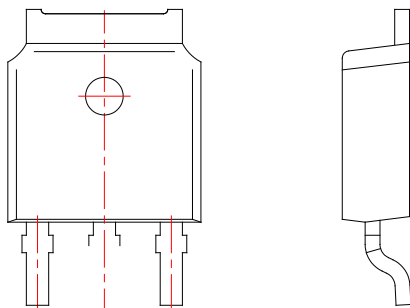
**ORDERING INFORMATION**

Order code	Voltage V <sub>DRM</sub> /V <sub>RRM</sub> (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
JCT1612K	1600	15	TO-252	80	Tube
JCT1612K-TR				2,500	Tape & Reel

**Document Revision History**

Date	Revision	Changes
Aug.10, 2023	A.	0 Tj .5&( 0 Tj .5&( 0 Tj)908.3 ( 2023)JTJ6.t023)J0 Tw)191.52 1 15 EMC /m7.

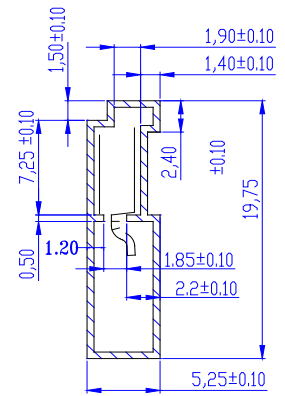
PACKAGE MECHANICAL DATA




Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10		2.50	0.083		0.098
A2	0		0.10	0		0.004
B	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
C	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1						
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
H	9.50		10.70	0.374		0.421
L	0.95		1.30	0.037		0.051
L2	1.35		1.75	0.053		0.069
V1		7°			7°	
V2	0°		6°	0°		6°



DELIVERY MODE



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